



#7/Amended
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P1296
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INFORMAL RESPONSE
DO NOT ENTER

PATENT
Docket No. P1296

IN THE
UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S): BIN YU
SERIAL NO.: 09/826,472 EXAMINER: RON E. POMPEY
FILED: APRIL 4, 2001 ART UNIT: 2812
FOR: METHOD OF FABRICATING A SEMICONDUCTOR DEVICE
HAVING A NITRIDE/HIGH-K/NITRIDE GATE DIELECTRIC STACK
BY ATOMIC LAYER DEPOSITION (ALD) (as amended)

BOX AF
COMMISSIONER FOR PATENTS
WASHINGTON, DC 20231

AMENDMENT AFTER FINAL REJECTION
UNDER 37 C.F.R. §1.116

To the Commissioner:

This letter is an Informal Response to the final Office Action dated January 28, 2003.
The Applicant hereby respectfully requests favorable consideration of the below-submitted amendment after final rejection, submitted under 37 C.F.R. §1.116, and remarks.